NSN 5962-01-356-4372

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View Online at https://aerobasegroup.com/nsn/5962-01-356-4372

Overall Length:
1.280 inches
Overall Height:
Between 0.325 inches and 0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.1 watts
Operating Tempurature Range:
-55.0 to 125.0 degrees celsius
Storage Tempurature Range:
-65.0 to 150.0 degrees celsius
Features Provided:
Monolithic and asynchronous and bidirectional and programmable and w/clock and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
22 input
Criticality Code Justification:
Nhcf
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
200.00 milliamperes supply
Terminal Surface Treatment:
Solder
Product Name:
And-or logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Pal
Nuclear Hardness Critical Feature:
Hardened

Hardened

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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